UNISONIC TECHNOLOGIES CO., LTD

UTG60N120FQ-G2

Preliminary

Insulated Gate Bipolar Transistor

1200V TRENCH GATE FIELD-STOP IGBT

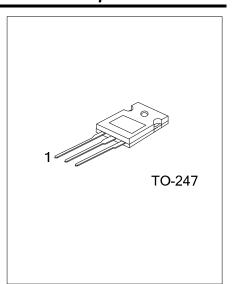
DESCRIPTION

The UTC **UTG60N120FQ-G2** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

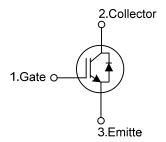
The UTC **UTG50N120FQ-G2** is suitable for the resonant or soft switching applications.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT).Typ.}$ = 1.68V @ I_C =60A, V_{GE} =15V (T_C =25°C)



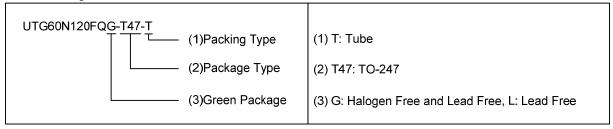
■ SYMBOL



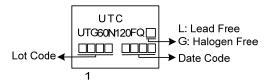
ORDERING INFORMATION

Ordering Number		Deslesses	Pin	Assignm	Da alainan		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG60N120FQL-T47-T	UTG60N120FQG-T47-T	TO-247	G	С	Е	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V _{CES}	1200	V	
Gate-Emitter Voltage		.,	±20	V	
Transient Gate-emitter voltage (tp < 5 ms)		V_{GES}	±25	V	
Continuous Collector Current	T _C =25°C	Ic	120	Α	
	T _C =100°C		60	Α	
Collector Current Pulsed (Note 1)		Ісм	240	Α	
Diada Famuand Cumant	T _C =25°C	l _F	72	Α	
Diode Forward Current	T _C =100°C		36	Α	
Short Circuit Withstand Time		tsc		μs	
V _{GE} = 15V, V _{CC} ≤ 200V					
Allowed number of short circuits < 1000			5		
Time between short circuits: ≥1.0s					
T _{VJ} = 25°C					
Power Dissipation (T _C =25°C)		P _D	285	W	
Operating Junction Temperature		T_J	-40 ~ +175	ů	
Storage Temperature Range		T _{STG}	-55 ~ +175	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	0.10	0.44	°C/W

^{2.} Pulse width limited by maximum junction temperature.

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS			TYP	MAX	UNIT		
Off Characteristics									
Collector-Emitter Breakdown Voltage	BV _{CES}			1200			V		
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V				250	μΑ		
G-E Leakage Current	I_{GES}	V _{CE} =0V, V _{GE} =±20V				±250	nA		
On Characteristics									
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	$I_C=250\mu A, V_{CE}=V_{GE}$	4.5		6.5	V			
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =60A, V _{GE} =15V	T _C =25°C		1.68	2.2	V		
			T _C =125°C		2.0		V		
Dynamic Characteristics									
Input Capacitance	CIES			6440		рF			
Output Capacitance	C_OES	V _{CE} =25V, V _{GE} =0V, f=1		126		pF			
Reverse Transfer Capacitance	C _{RES}				63.5		pF		
Switching Characteristics	_								
Total Gate Charge	Q_{G}				282		nC		
Gate-Emitter Charge	Q_GE	V _{CE} =600V, I _C =60A, V _G		55		nC			
Gate-Collector Charge	Q_{GC}				145		nC		
Turn-On Delay Time	t _{DON)}			37.9		ns			
Rise Time	t_{R}	V _{CC} =600V, I _C =60A, R _G =5Ω, V _{GE} =0~15V, L=500μH			41.9		ns		
Turn-Off Delay Time	t _{DOFF)}				256.3		ns		
Fall Time	t _F				245.7		ns		
Turn-On Switching Loss	Eon				4.258		mJ		
Turn-Off Switching Loss	E _{OFF}	<u> </u>			5.007		mJ		
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS									
Forward Voltage Drop	V _F	I _F =60A				3.5	V		
Reverse Recovery Time	t _{rr}	160		63.7		ns			
Reverse Recovery Charge	Qrr	I _F =60A, dI/dt=100A/µS, V _{CC} =400V			1323		nC		

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